NL17SH34

Single Buffer

The NL17SH34 MiniGate[™] is an advanced high-speed CMOS Buffer in ultra-small footprint.

The NL17SH34 input structure provides protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

Features

- High Speed: $t_{PD} = 3.5$ ns (Typ) at $V_{CC} = 5.0$ V
- Low Power Dissipation: $I_{CC} = 1.0 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays

IN A

GND

NC 3

IN A

2

- Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Package
- These are Pb-Free and Halide-Free Devices

 \bigcirc

5 V_{CC}

4

Figure 1. Pinout (Top View)

1

Figure 2. Logic Symbol

OUT Y

OUT Y



ON Semiconductor®

http://onsemi.com

MARKING DIAGRAM



2



= Specific Device Code (Rotated 90°)

SOT-953

= Month Code Μ

PIN ASSIGNMENT						
1	IN A					
2	GND					
3	NC					
4	OUT Y					
5	V _{CC}					

FUNCTION TABLE

A Input	Y Output
L	L
Н	Н

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Param	neter	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage		-0.5 to +7.0	V
V _{OUT}	DC Output Voltage	V _{IN} = 0 High or Low State	-0.5 to +7.0 -0.5 to V _{CC} +0.5	V
I _{IK}	DC Input Diode Current	V _{IN} < GND	-20	mA
I _{OK}	DC Output Diode Current	V_{OUT} < GND, V_{OUT} > V_{CC}	±20	mA
I _{OUT}	DC Output Source/Sink Current		±25	mA
I _{CC}	DC Supply Current per Supply Pin		50	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 S	Seconds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	>2000 >200 N/A	V
I _{LATCHUP}	Latchup Performance Abo	ve V _{CC} and Below GND at 125°C (Note 5)	±100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	1.65	5.5	V	
V _{IN}	Digital Input Voltage	0.0	5.5	V	
V _{OUT}	Output Voltage		0.0	V _{CC}	V
T _A	Operating Temperature Range		-55	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fail Rate V _C V _C	$_{\rm C} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $_{\rm C} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

DC ELECTRICAL CHARACTERISTICS

			V _{cc}	Т	A = 25°	C	T _A ≤	85°C	-55°C 1	to 125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		1.65 to 2.0	0.75 x V _{CC}			0.75 x V _{CC}				V
			2.3 to 5.5	0.70 x V _{CC}			0.70 x V _{CC}				
V _{IL}	Low-Level Input Voltage		1.65 to 2.0			0.25 x V _{CC}		0.25 x V _{CC}		0.25 x V _{CC}	V
			2.3 to 5.5			0.30 x V _{CC}		0.30 x V _{CC}		0.30 x V _{CC}	
V _{OH}	High-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \ \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		1.9 2.9 4.4		V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66		
V _{OL}	Low-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \ \mu A$	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	
I _{IN}	Input Leakage Current	$V_{IN} = 5.5 \text{ V or GND}$	0 to 5.5			±0.1		±1.0		±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1.0		10		40	μA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

		V _{cc}	Test	Г	A = 25°C		T _A ≤	85°C	−55°C t	to 125°C	
Symbol	Parameter	(V)	Conditions	Min	Тур	Max	Min	Max	Min	Мах	Unit
t _{PLH} , t _{PHL}	Propagation Delay, A to Y	3.0 to 3.6	C _L = 15 pF C _L = 50 pF		4.5 6.4	7.1 10.6		8.5 12.0		10.0 14.5	ns
		4.5 to 5.5	C _L = 15 pF C _L = 50 pF		3.5 4.5	5.5 7.5		6.5 8.5		8.0 10.0	
C _{IN}	Input Capacitance				4.0	10		10		10	pF
C _{PD}	Power Dissipation Capacitance (Note 6)	5.0			8.0						pF

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

NL17SH34

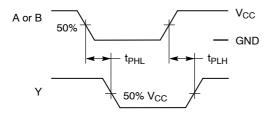


Figure 3. Switching Waveforms

DEVICE UNDER TEST

*Includes all probe and jig capacitance.

Figure 4. Test Circuit

ORDERING INFORMATION

Device	Device Package	
NL17SH34P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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SCALE 4:1

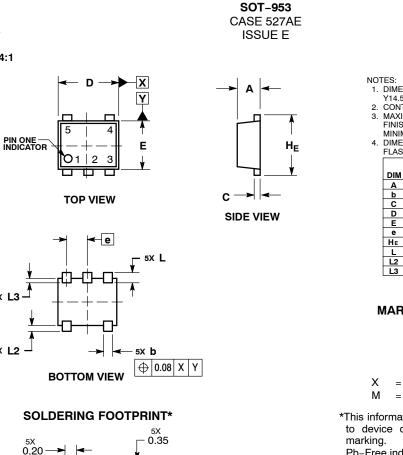
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





DATE 02 AUG 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	МІ	LIMETE	RS					
DIM	MIN NOM MAX							
Α	0.34	0.37	0.40					
b	0.10	0.15	0.20					
С	0.07	0.12	0.17					
D	0.95	1.00	1.05					
E	0.75	5 0.80 0.85						
е		0.35 BS	С					
HE	0.95	1.00	1.05					
L	(0.175 RE	F					
L2	0.05	0.10	0.15					
L3			0.15					

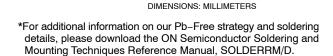
GENERIC **MARKING DIAGRAM***

= Specific Device Code

= Month Code

*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



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